

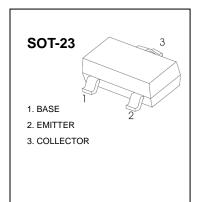
TRANSISTOR(NPN)

FEATURES

• Complimentary to S8550

• Collector Current: I_C=0.5A

MARKING: J3Y



MAXIMUM RATINGS (T_A=25℃ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|------------------|-------------------------------|---------|------------|
| V _{CBO} | Collector-Base Voltage | 40 | V |
| V _{CEO} | Collector-Emitter Voltage | 25 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| Ic | Collector Current -Continuous | 0.5 | А |
| Pc | Collector Dissipation | 0.3 | W |
| Tj | Junction Temperature | 150 | $^{\circ}$ |
| T _{stg} | Storage Temperature | -55-150 | °C |

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

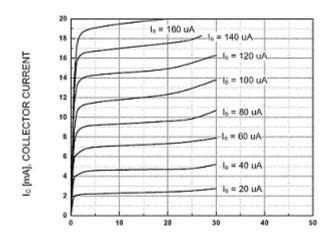
| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|-----------------------|---|-----|-----|-----|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | I _C = 100 μ A, I _E =0 | 40 | | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | I _C =1mA, I _B =0 | 25 | | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _E =100 μ A, I _C =0 | 5 | | | V |
| Collector cut-off current | I _{CBO} | V _{CB} =40 V , I _E =0 | | | 0.1 | μА |
| Emitter cut-off current | I _{EBO} | V _{EB} = 5V , I _C =0 | | | 0.1 | μА |
| DC ourrent gain | H _{FE(1)} | V _{CE} =1V, I _C = 50mA | 120 | | 350 | |
| DC current gain | H _{FE(2)} | V _{CE} =1V, I _C = 500mA | 50 | | | |
| Collector-emitter saturation voltage | V _{CE} (sat) | I _C =500 mA, I _B = 50mA | | | 0.6 | V |
| Base-emitter saturation voltage | V _{BE} (sat) | I _C =500 mA, I _B = 50mA | | | 1.2 | V |
| Transition frequency | f⊤ | V _{CE} =6V, I _C = 20mA f=30MHz | 150 | | | MHz |

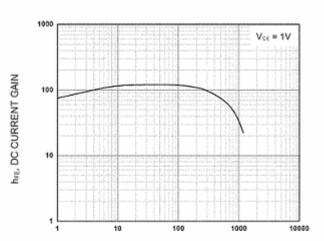
CLASSIFICATION OF h_{FE(1)}

| Rank | L | Н |
|-------|---------|---------|
| Range | 120-200 | 200-350 |







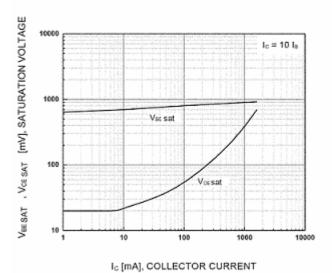


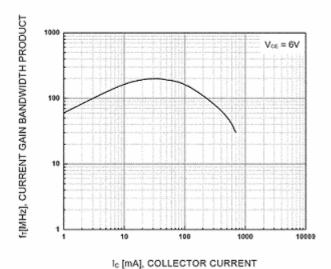
 V_{CE} [V], COLLECTOR-EMITTER VOLTAGE

Ic [mA], COLLECTOR CURRENT

Static Characteristic

DC current Gain





Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

Current Gain Bandwidth Product

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